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RCD100N20

Nch 200V 10A Power MOSFET

V_{DSS}	200V
R _{DS(on)} (Max.)	182m Ω
I _D	10A
P_D	85W

Features

- 1) Low on-resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating; RoHS compliant
- 6) 100% Avalanche tested

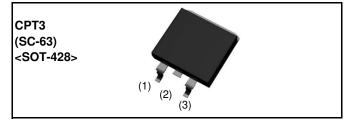
Application

Switching Power Supply

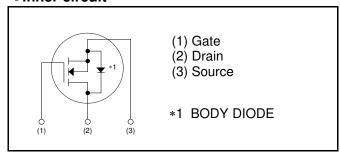
Automotive Motor Drive

Automotive Solenoid Drive

Outline



●Inner circuit



Packaging specifications

	Packaging	Taping
	Reel size (mm)	330
Tuno	Tape width (mm)	16
Туре	Basic ordering unit (pcs)	2,500
	Taping code	TL
	Marking	C10N20

● Absolute maximum ratings (T_a = 25°C)

Parameter	Symbol	Value	Unit	
Drain - Source voltage		V_{DSS}	200	V
Continuous drain current	$T_c = 25^{\circ}C$	I _D *1	±10	А
Continuous drain current	$T_c = 100$ °C	l _D *1	±5.4	Α
Pulsed drain current		I _{D,pulse} *2	±40	А
Gate - Source voltage		V_{GSS}	±30	V
Avalanche energy, single pulse		E _{AS} *3	7.35	mJ
Avalanche current		I _{AS} *3	5.0	Α
T _c = 25°C		P_{D}	85	W
Power dissipation $T_a = 25^{\circ}C^{*4}$		P _D	0.85	W
Junction temperature		T _j	150	°C
Range of storage temperature	T _{stg}	-55 to +150	°C	

●Thermal resistance

Parameter	Symbol	Values			Unit
Farameter	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - case	R_{thJC}	-	-	1.46	°C/W
Thermal resistance, junction - ambient *4	R_{thJA}	-	-	147	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Farameter	Symbol	Conditions	Min.	Тур.	Max.	UTIIL
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V$, $I_D = 1mA$	200	-	-	V
		$V_{DS} = 200V, V_{GS} = 0V$			10	
Zero gate voltage		$T_j = 25^{\circ}C$	-	-	10	μΑ
drain current	I _{DSS}	$V_{DS} = 200V, V_{GS} = 0V$	-		100	
		T _j = 125°C				
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 30V, \ V_{DS} = 0V$	-	-	±100	nA
Gate threshold voltage	V _{GS (th)}	$V_{DS} = 10V$, $I_D = 1mA$	3.25	-	5.25	V
		$V_{GS} = 10V, I_D = 5.0A$	-	140	182	
Static drain - source on - state resistance	$R_{DS(on)}^{ \ *5}$	$V_{GS} = 10V, I_D = 5.0A$		200	265	mΩ
		T _j = 125°C	-	- 280	365	
Forward transfer admittance	g _{fs}	$V_{DS} = 10V, I_{D} = 5.0A$	2.1	4.2	-	S

●Electrical characteristics (T_a = 25°C)

Parameter	Symbol	Conditions	Values			Unit
r arameter	Syllibol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	C_{iss}	$V_{GS} = 0V$	-	1400	-	
Output capacitance	C _{oss}	V _{DS} = 25V	-	95	-	pF
Reverse transfer capacitance	C_{rss}	f = 1MHz	-	45	-	
Turn - on delay time	$t_{d(on)}$ *5	$V_{DD} \simeq 100V, V_{GS} = 10V$	-	25	-	
Rise time	t _r *5	$I_{D} = 5.0A$	-	35	-	nc
Turn - off delay time	$t_{d(off)}$ *5	$R_L = 20\Omega$	-	40	-	ns
Fall time	t _f *5	$R_G = 10\Omega$	-	15	-	

● Gate Charge characteristics (T_a = 25°C)

Darameter	Cymbol	Conditions		Values		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	Q_g^{*5}	$V_{DD} \simeq 100V$	-	25	-	
Gate - Source charge	Q _{gs} *5	I _D = 10A	-	9	-	nC
Gate - Drain charge	Q _{gd} *5	$V_{GS} = 10V$	-	9	-	
Gate plateau voltage	V _(plateau)	$V_{DD} \simeq 100V, I_D = 10A$	-	7.3	-	V

●Body diode electrical characteristics (Source-Drain)(T_a = 25°C)

Parameter	Symbol Conditions		Values			Unit
- Farameter	Symbol	mbol Conditions -		Тур.	Max.	Offic
Continuous source current	l _S *1	T _c = 25°C	-	ı	10	Α
Pulsed source current	I _{SM} *2	1 _c = 25 0	-	-	40	Α
Forward voltage	V _{SD} *5	$V_{GS} = 0V, I_{S} = 10A$	-	-	1.5	V
Reverse recovery time	t _{rr} *5	I _S = 5.0A	-	85	-	ns
Reverse recovery charge	Q _{rr} *5	di/dt = 100A/μs	-	270	-	nC

^{*1} Limited only by maximum temperature allowed.

*5 Pulsed

^{*2} Pw \leq 10 μ s, Duty cycle \leq 1%

^{*3} L \simeq 500 μ H, V_{DD} = 50V, Rg = 25 Ω , starting T_j = 25°C

^{*4} Mounted on a epoxy PCB FR4 (20mm × 20mm × 0.8mm)

Fig.1 Power Dissipation Derating Curve

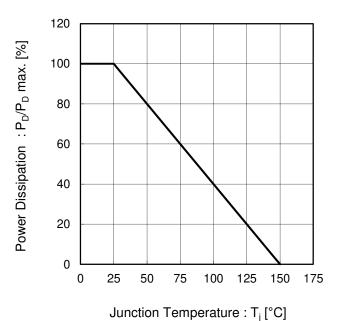
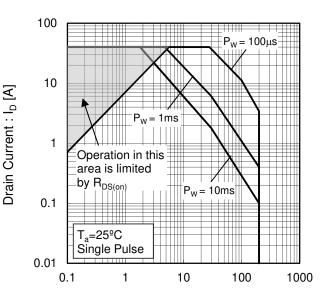
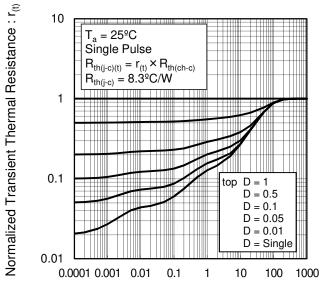


Fig.2 Maximum Safe Operating Area



Drain - Source Voltage : V_{DS} [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width: Pw [s]

Fig.4 Avalanche Current vs Inductive Load

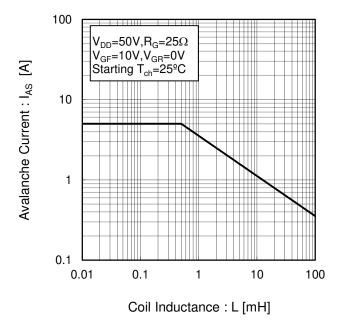
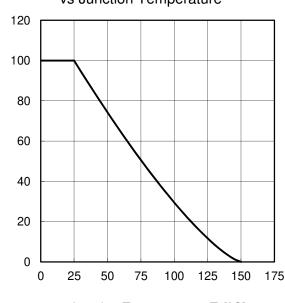


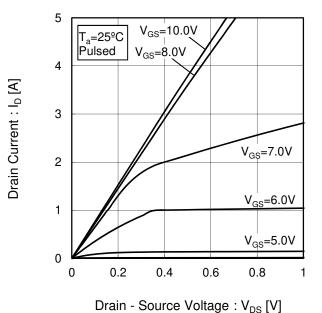
Fig.5 Avalanche Energy Derating Curve vs Junction Temperature



Junction Temperature : T_j [°C]

Fig.7 Typical Output Characteristics(II)

Fig.6 Typical Output Characteristics(I)

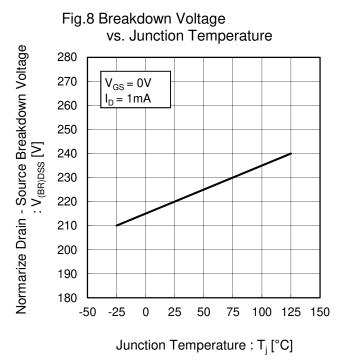


Drain Current : I_D [A]

Avalanche Energy: E_{AS} / E_{AS} max. [%]

10 T_a=25ºC V_{GS}=10.0V Pulsed V_{GS}=8.0V 8 6 V_{GS}=7.0V 4 V_{GS}=6.0V 2 $V_{GS}=5.0V$ 0 2 0 4 6 8 10

Drain - Source Voltage: V_{DS} [V]



100 $V_{DS} = 10V$ 10 Drain Current : I_D [A] 0.1 T_a= 125ºC $T_a = 75^{\circ}C$ $T_a = 25^{\circ}C$ 0.01 –25ºC 0.001 2 3 5 8 0 4 6 9 10

Gate - Source Voltage : V_{GS} [V]

Fig.9 Typical Transfer Characteristics

Fig.10 Gate Threshold Voltage vs. Junction Temperature 5.0 $V_{DS} = 10V$ Gate Threshold Voltage: V_{GS(th)} [V] $I_D = 1 \text{mA}$ 4.5 4.0 3.5 3.0 -50 -25 0 25 50 75 100 125 150 Junction Temperature : T_i [°C]

10 $V_{DS} = 10V$ Transconductance: gfs [S] 1 –25ºC _=25ºC 0.1 _=75ºC a=125ºC 0.01 0.01 0.1 1 10 100 Drain Current: I_D [A]

Fig.11 Transconductance vs. Drain Current



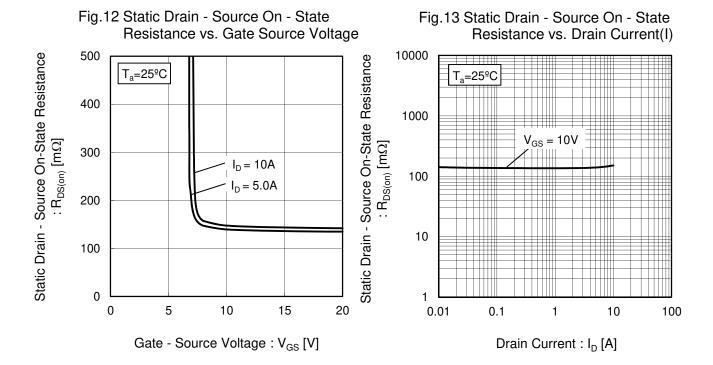
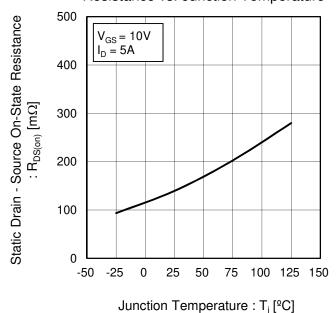


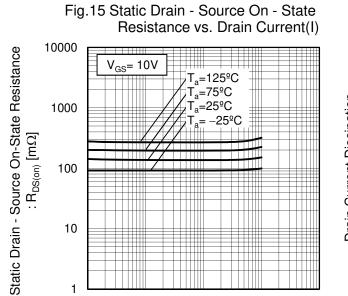
Fig.14 Static Drain - Source On - State
Resistance vs. Junction Temperature



0.01

0.1

• Electrical characteristic curves



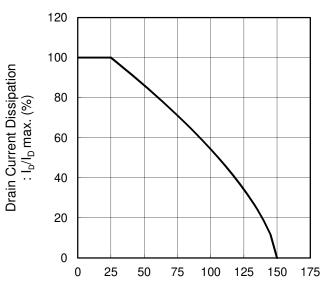
Drain Current : I_D [A]

1

10

100

Fig.16 Drain Current Derating Curve



Junction Temperature : T_i [°C]

10

0.01

• Electrical characteristic curves

= 25ºC

0.1

= 1MHz = 0V

Fig.17 Typical Capacitance vs. Drain - Source Voltage 10000 1000 Capacitance: C [pF] Cos 100

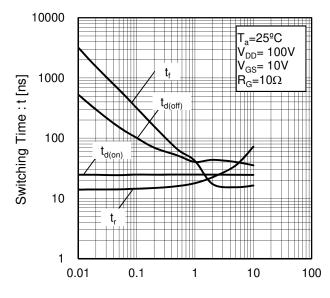
Drain - Source Voltage : $V_{DS}[V]$

10

100

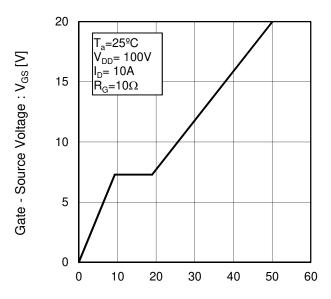
1000

Fig.18 Switching Characteristics



Drain Current : I_D [A]

Fig.19 Dynamic Input Characteristics



Total Gate Charge : Q_g [nC]

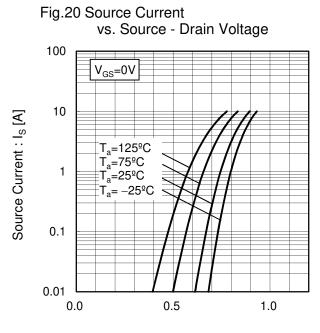


Fig21 Reverse Recovery Time

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

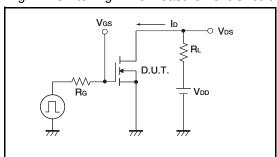


Fig.2-1 Gate Charge Measurement Circuit

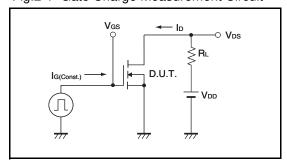


Fig.3-1 Avalanche Measurement Circuit

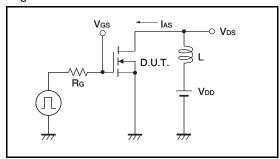


Fig.1-2 Switching Waveforms

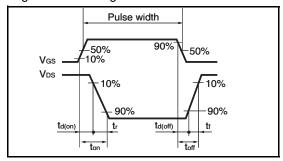


Fig.2-2 Gate Charge Waveform

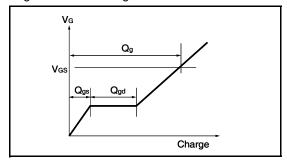
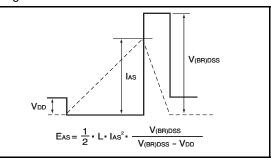
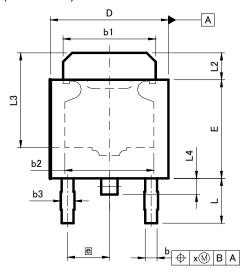


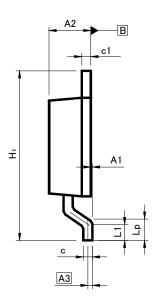
Fig.3-2 Avalanche Waveform

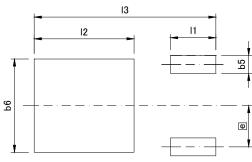


●Dimensions (Unit:mm)









DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
A1	0.00	0.15	0	0.006
A2	2.20	2.50	0.087	0.098
A3	0.:	25	0.0	01
b	0.55	0.75	0.022	0.03
b1	5.00	5.30	0.197	0.209
b2	5.0	00	0.:	20
b3	0.	75	0.0	03
С	0.40	0.60	0.016	0.024
c1	0.40	0.60	0.016	0.024
D	6.30	6.70	0.248	0.264
Е	5.40	5.80	0.213	0.228
е	2.3	30	0.0	09
HE	9.00	10.00	0.354	0.394
L	2.20	2.80	0.087	0.11
L1	0.80	1.40	0.031	0.055
L2	1.20	1.80	0.047	0.071
L3	5.30		0.209	
L4	0.9	90	0.0	35
Lp	1.00	1.60	0.039	0.063
х	_	0.25	_	0.01

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
b5	-	1.00	-	0.04
b6	-	5.20	-	0.205
11	-	2.50	-	0.098
12	-	5.50	-	0.217
13	-	10.00	-	0.394

Dimension in mm/inches

Rev.003

Notice

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JAPAN	USA	EU	CHINA
CLASSⅢ	CL ACCTI	CLASS II b	СГУССШ
CLASSIV	CLASSII	CLASSⅢ	CLASSⅢ

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 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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